

## TO-247 Plastic-Encapsulate Diode

### MURW30H20CTB HYPERFAST RECTIFIER,FRED

#### MAIN CHARACTERISTICS

$I_o$	<b>30(15×2)A</b>
$V_{RRM}$	<b>200V</b>
$T_{rr}$	<b>14ns</b>
$T_j$	<b>175°C</b>
$V_{F(typ)}$	<b>0.75V(@<math>T_j=150°C</math>)</b>

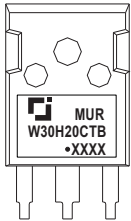
#### FEATURES

- Ultrafast Recovery Times and Low Recovery Loss
- Low Forward Voltage
- Low Reverse Leakage Current

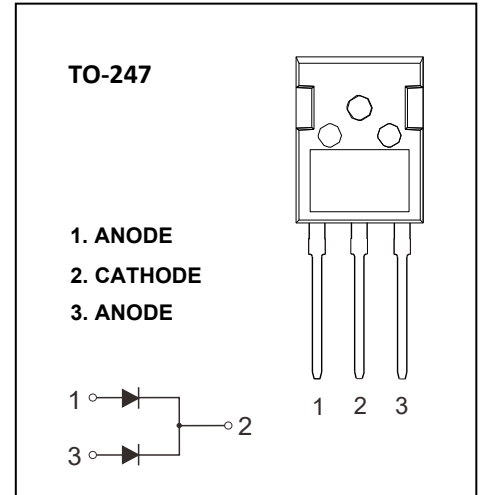
#### APPLICATIONS

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

#### MARKING



MURW30H20CTB = Device code  
 Solid dot = Green molding compound device  
 if none, the normal device  
 XXXX = Code



#### MAXIMUM RATINGS ( $T_c=25°C$ unless otherwise noted )

Symbol	Parameter	MURW30H20CTB	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage	200	V
$V_R$	DC Blocking Voltage		
$I_{F(AV)}$	Average rectified output current@ Per leg( $T_c=153°C$ )	15	A
	Average rectified output current@ Total device( $T_c=153°C$ )	30	
$I_{F(RMS)}$	RMS Forward Current( $T_c=153°C$ )	21	A
$I_{FSM}$	Non-Repetitive Surge Forward Current (8.3ms)	250	A
$P_D$	Power dissipation	167	W
$R_{\theta JC}$	Thermal Resistance From Junction to Case	0.9	°C/W
$T_j$	Operating Junction Temperature Range	-55 ~ +175	°C
$T_{stg}$	Storage Temperature Range	-55 ~ +175	°C

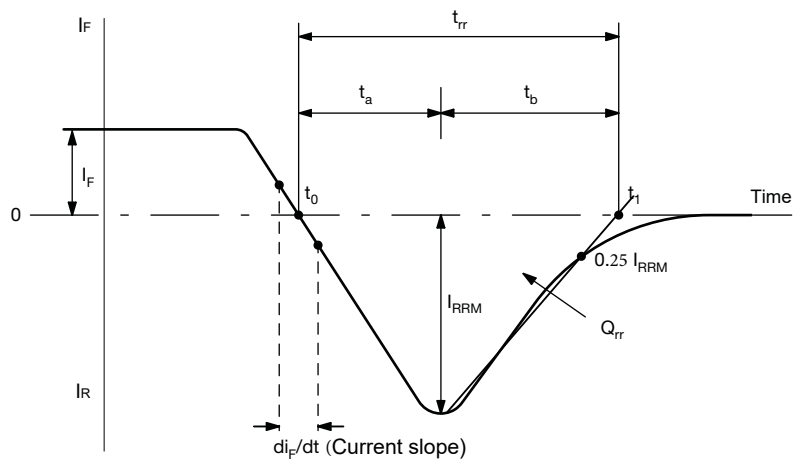
# Typical Characteristics

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)}$	Reverse Voltage	$I_R=100\mu\text{A}$	200			V
$I_R$	Reverse Current	$V_R=200\text{V}$	$T_j=25^\circ\text{C}$		1	$\mu\text{A}$
			$T_j=150^\circ\text{C}$		500	$\mu\text{A}$
$V_F$	Forward Voltage	$I_F=15\text{A}$	$T_j=25^\circ\text{C}$	0.93	1.0	V
			$T_j=150^\circ\text{C}$	0.75		V
$C_{tot}$	Total Capacitance	$V_R=200\text{V}, f=1\text{MHz}$		50		pF
$t_{rr}$	Reverse Recovery time	$I_F=0.5\text{A}, I_R=1\text{A}, I_{rr}=0.25\text{A}$		19		ns
		$I_F=1\text{A}, V_R=30\text{V}, di_F/dt = 200\text{A}/\mu\text{s}$		14		ns

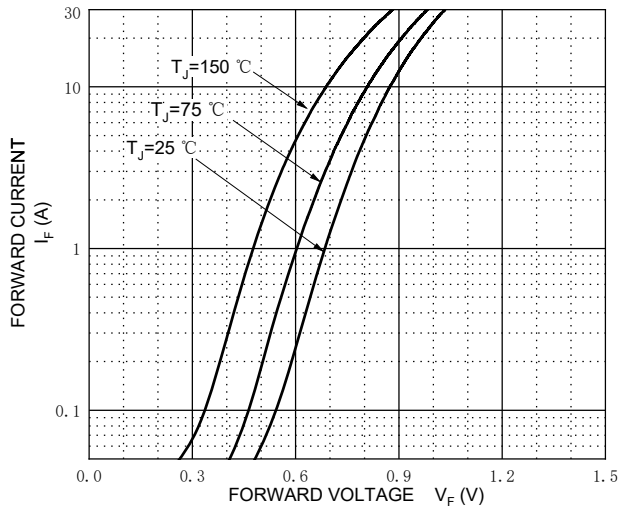
## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=100\text{V}, di_F/dt=200\text{A}/\mu\text{s}$		13		ns
$I_{RRM}$	Max. Reverse Recovery Current		2.0		A	
$Q_{rr}$	Reverse Recovery Charge		13		nC	
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=100\text{V}, di_F/dt=200\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		27		ns
$I_{RRM}$	Max. Reverse Recovery Current		5.0		A	
$Q_{rr}$	Reverse Recovery Charge		64		nC	
$t_{rr}$	Reverse Recovery Time	$I_F=15\text{A}, V_R=100\text{V}, di_F/dt=600\text{A}/\mu\text{s}, T_j=125^\circ\text{C}$		22		ns
$I_{RRM}$	Max. Reverse Recovery Current		12		A	
$Q_{rr}$	Reverse Recovery		141		nC	

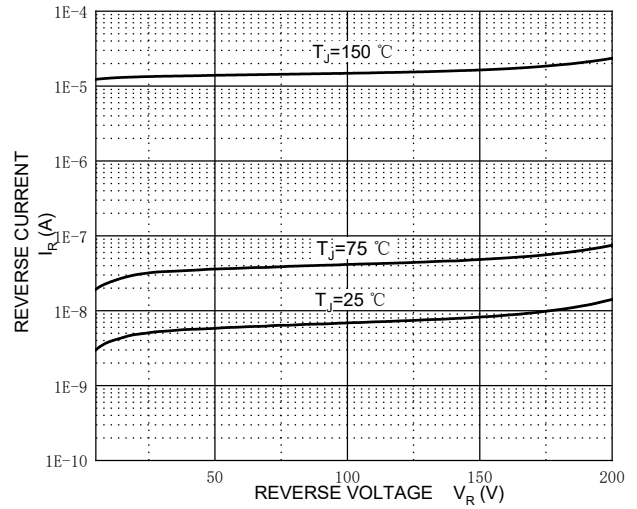


Reverse Recovery Waveform and Definitions

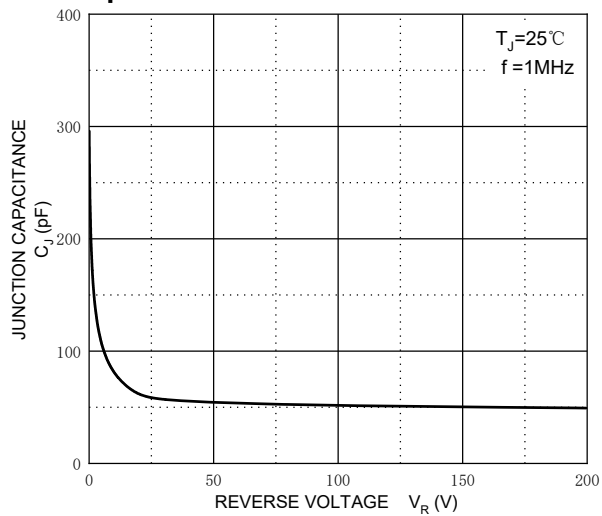
### Forward Characteristics



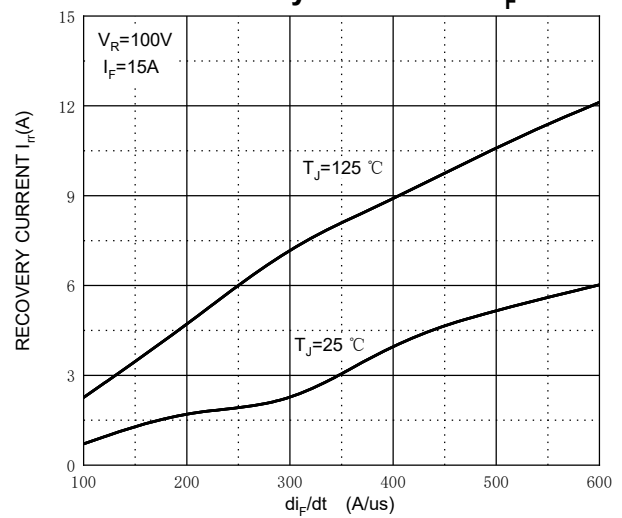
### Reverse Characteristics



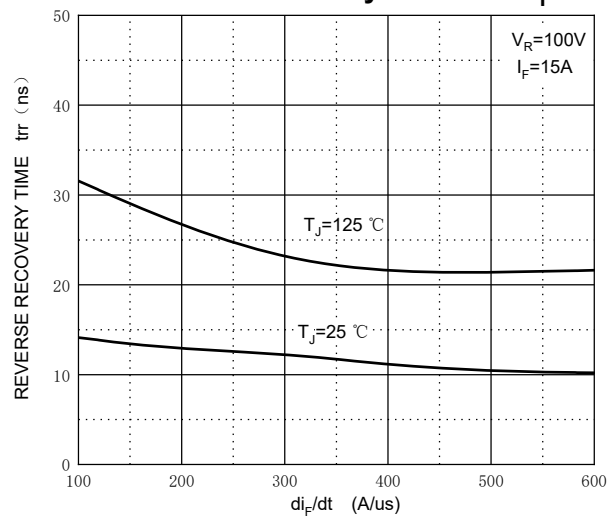
### Capacitance Characteristics Per Diode



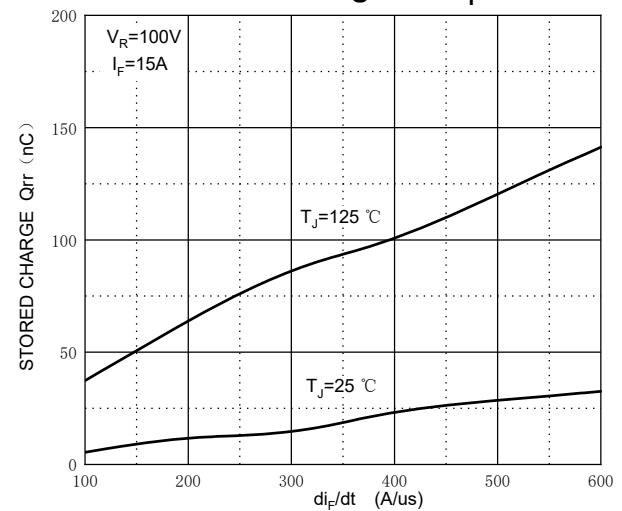
### Recovery Current vs. $di_F/dt$



### Reverse Recovery Time vs. $di_F/dt$

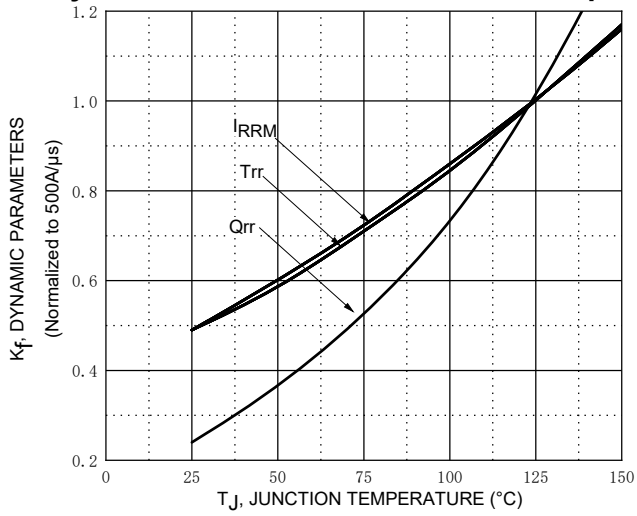


### Stored Charge vs. $di_F/dt$

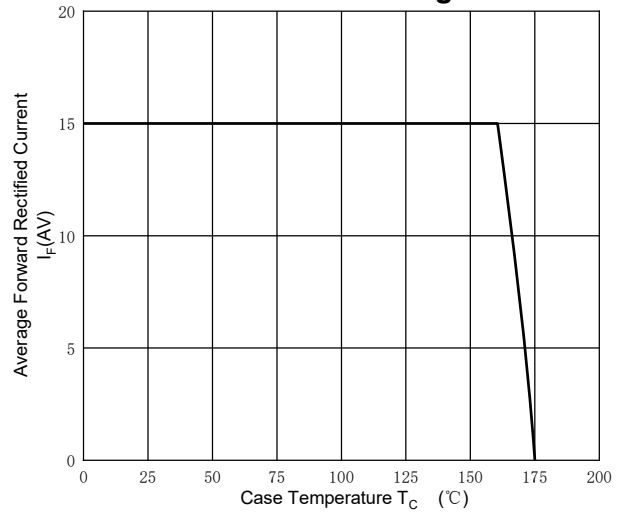


# Typical Characteristics

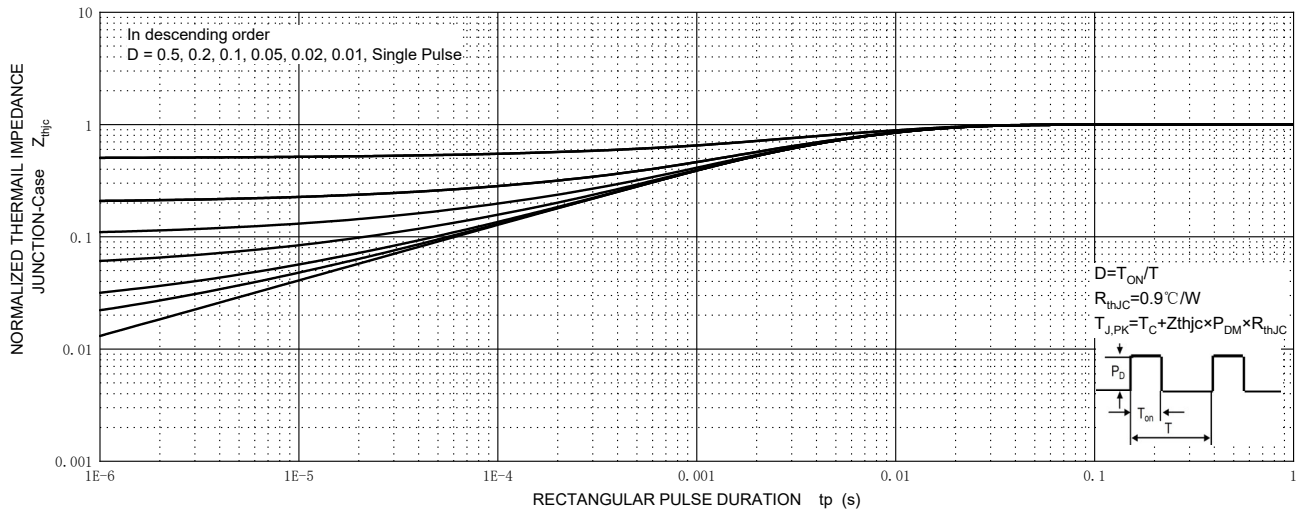
## Dynamic Parameters vs. Junction Temperature



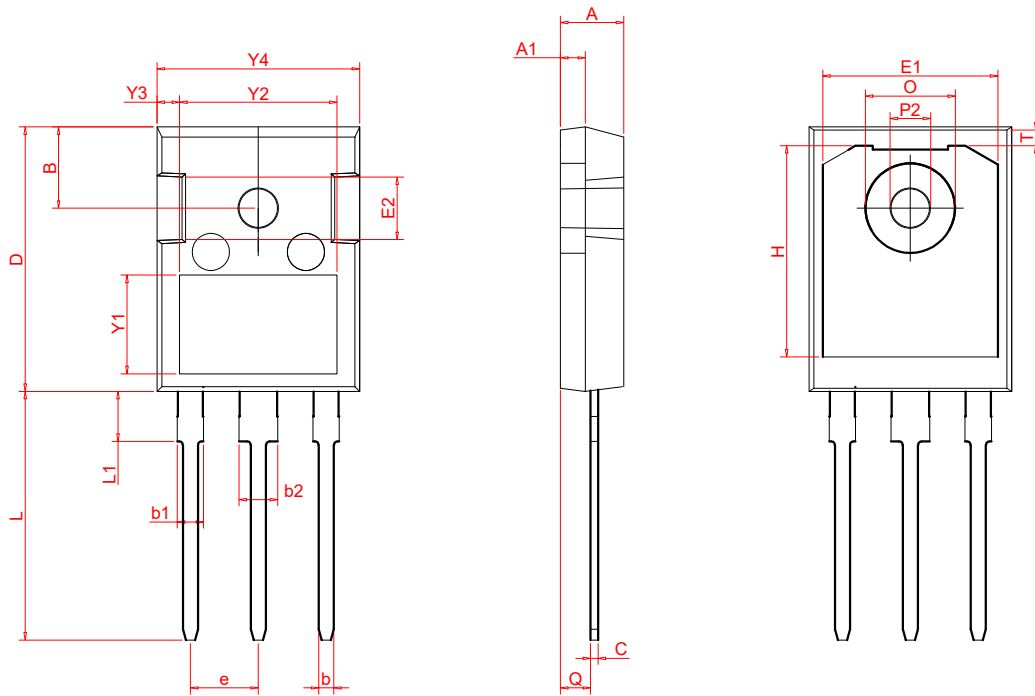
## Current Derating



## MURW30H20CTB Transient Thermal Impedance, Junction-Case



# TO-247 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.700	5.300	0.185	0.209
A1	1.700	2.300	0.067	0.091
C	0.450	0.750	0.018	0.030
Q	2.200	2.600	0.087	0.102
O	7.100	7.400	0.280	0.291
P2	3.450	3.750	0.136	0.148
L	19.000	21.000	0.748	0.827
L1	4.2	4.5	0.165	0.177
b	1.000	1.400	0.039	0.055
b1	1.800	2.250	0.071	0.089
b2	3.000	3.300	0.118	0.130
e	5.250	5.550	0.207	0.219
D	20.950	21.350	0.825	0.841
Y1	7.600	8.100	0.299	0.319
Y2	11.000	13.000	0.433	0.512
Y3	1.750	2.250	0.069	0.089
Y4	16.000	16.400	0.630	0.646
E2	4.600	4.900	0.181	0.193
T	1.35REF		0.053REF	
H	16.25REF		0.639REF	
E1	14REF		0.551REF	
B	6.55REF		0.257REF	